

20 V, P-channel Trench MOSFET 28 July 2014

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.0 × 0.6 × 0.37 mm
- ElectroStatic Discharge (ESD) protection > 1 kV HBM
- Drain-source on-state resistance R_{DSon} = 1.02 Ω

3. Applications

- Relay driver
- High-speed line driver
- High-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-500	mA
Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -500 mA; T _j = 25 °C		-	1.02	1.4	Ω

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².

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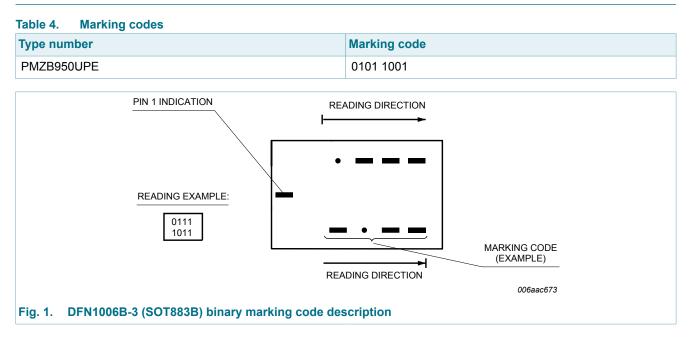
5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	1	D
2	S	source	2	
3	D	drain	Transparent top view DFN1006B-3 (SOT883B)	G S 017aaa259

6. Ordering information

Table 3. Ordering inf	formation		
Type number	Package		
	Name	Description	Version
PMZB950UPE	DFN1006B-3	DFN1006B-3: leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B

7. Marking



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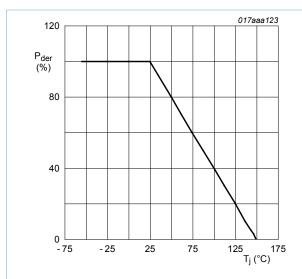
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

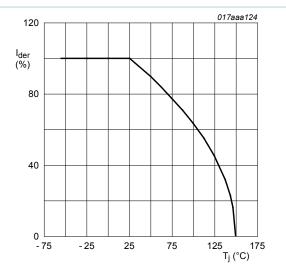
Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
ID	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-500	mA
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-300	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-2	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	360	mW
			[1]	-	715	mW
		T _{sp} = 25 °C		-	2700	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode	,				
I _S	source current	T _{amb} = 25 °C	[1]	-	-350	mA

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.





$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$





$$I_{der} = \frac{I_D}{I_{D(25^\circ C)}} \times 100 \%$$

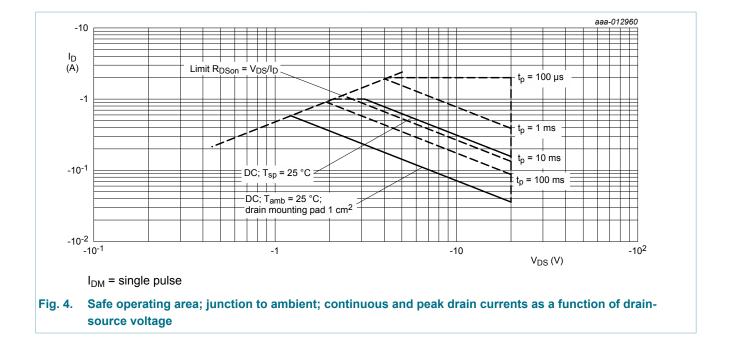
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9. Thermal characteristics

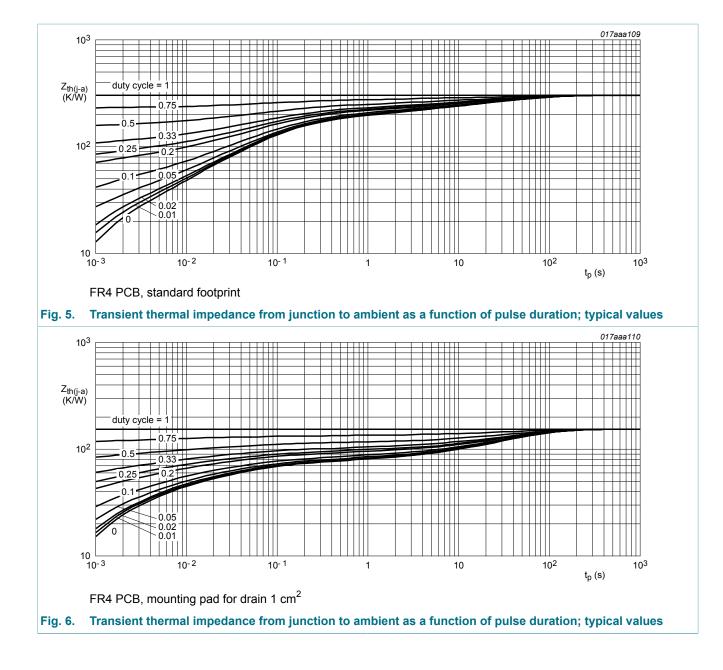
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	305	360	K/W
			[2]	-	150	175	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	40	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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10. Characteristics

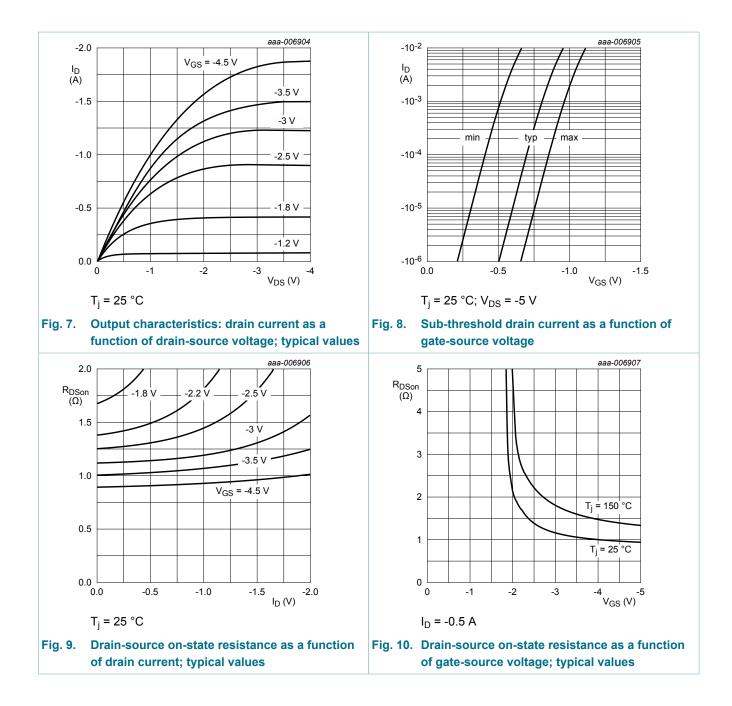
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	acteristics	l				
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 150 °C	-	-	-10	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -500 mA; T _j = 25 °C	-	1.02	1.4	Ω
		V _{GS} = -4.5 V; I _D = -500 mA; T _j = 150 °C	-	1.54	2.1	Ω
		V_{GS} = -2.5 V; I _D = -200 mA; T _j = 25 °C	-	1.27	2.2	Ω
		V _{GS} = -1.8 V; I _D = -40 mA; T _j = 25 °C	-	1.7	3.3	Ω
		V _{GS} = -1.5 V; I _D = -10 mA; T _j = 25 °C	-	2.3	5	Ω
		V _{GS} = -1.2 V; I _D = -1 mA; T _j = 25 °C	-	3.5	-	Ω
9 _{fs}	forward transconductance	V_{DS} = -10 V; I _D = -500 mA; T _j = 25 °C	-	480	-	mS
Dynamic ch	aracteristics	1	I			
Q _{G(tot)}	total gate charge	V _{DS} = -10 V; I _D = -450 mA;		1.19	2.1	nC
Q _{GS}	gate-source charge	V _{GS} = -4.5 V; T _j = 25 °C	-	0.17	-	nC
Q _{GD}	gate-drain charge		-	0.1	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	43	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	14	-	pF
C _{rss}	reverse transfer capacitance		-	8	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -0.45 A; R _L = 22 Ω;	-	2.3	-	ns
t _r	rise time	V _{GS} = -4.5 V; R _{G(ext)} = 6 Ω; T _j = 25 °C	-	5	-	ns
t _{d(off)}	turn-off delay time		-	13.5	-	ns
t _f	fall time		-	6	-	ns
Source-drai	in diode	1				
V _{SD}	source-drain voltage	I _S = -115 mA; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V

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Product data sheet

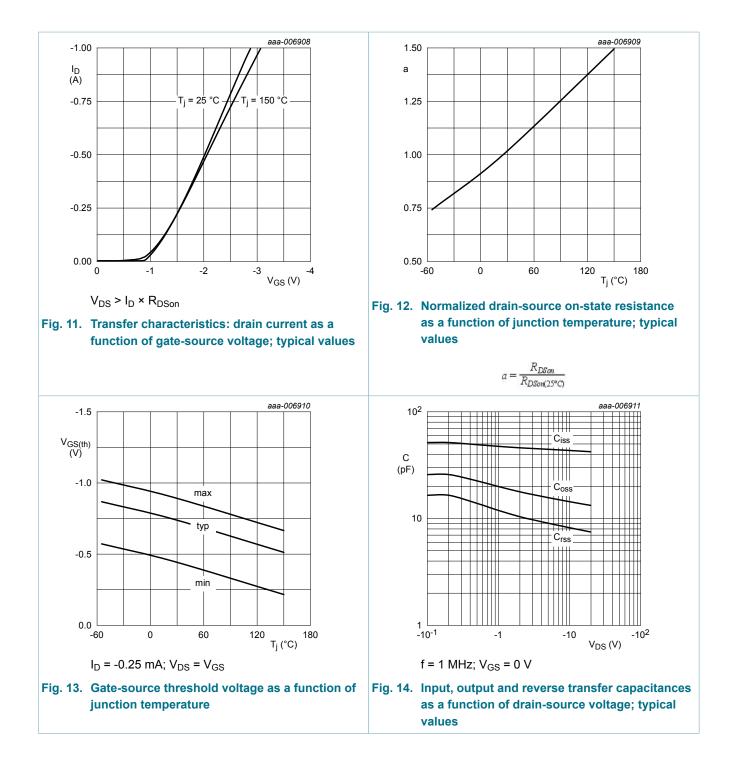
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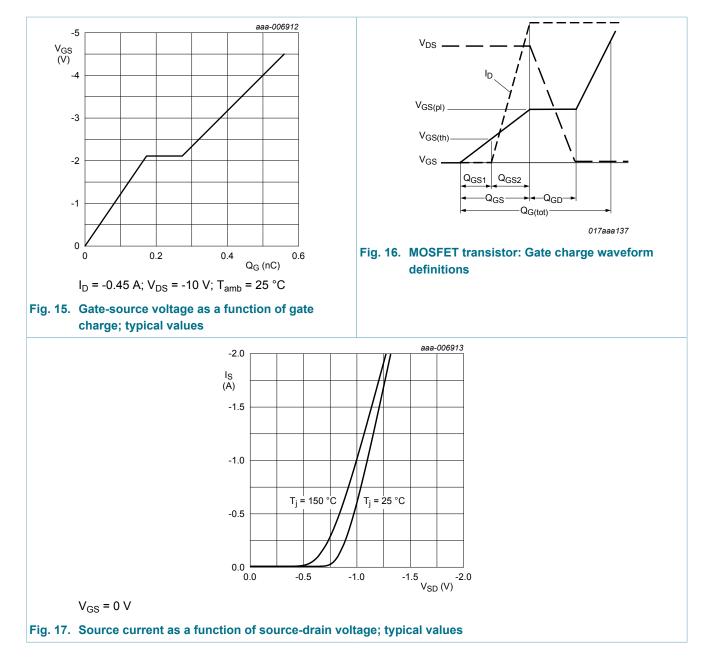


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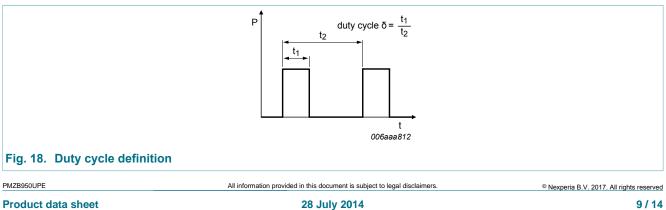
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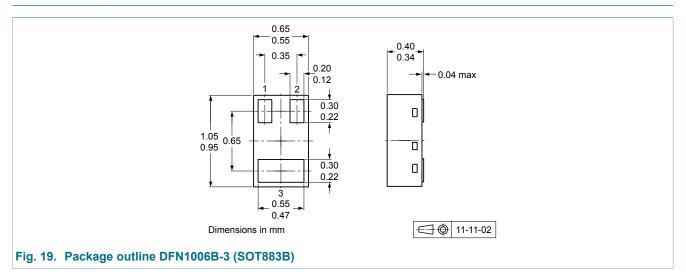
11. Test information



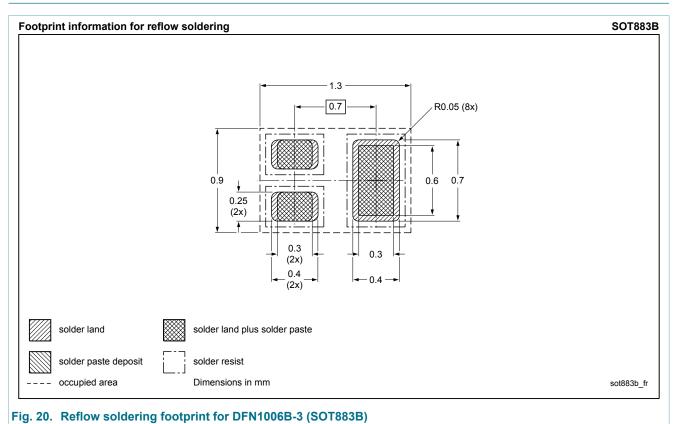
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12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMZB950UPE v.1	20140728	Product data sheet	-	-			

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15. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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